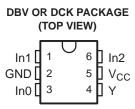


CONFIGURABLE MULTIPLE-FUNCTION GATE

FEATURES

- Qualified for Automotive Applications
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 7.3 ns at 3.3 V
- Low Power Consumption, 10-μA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



DESCRIPTION/ORDERING INFORMATION

This configurable multiple-function gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G98-Q1 features configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and noninverter. All inputs can be connected to V_{CC} or GND.

This device functions as an independent gate, but because of Schmitt action, it may have different input threshold levels for positive-going $(V_{T_{+}})$ and negative-going $(V_{T_{-}})$ signals.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION(1)

T _A	PACKAG	E ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING (3)
–40°C to 125°C	SOT (SOT-23) - DBV	Tape and reel	SN74LVC1G98QDBVRQ1	C98_
-40°C to 125°C	SOT (SC-70) - DCK	Tape and reel	SN74LVC1G98QDCKRQ1	CW_

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

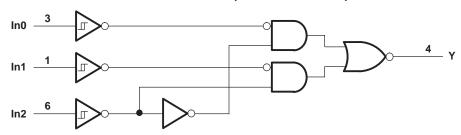
⁽³⁾ DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.



FUNCTION TABLE

	INPUTS	OUTPUT	
ln2	ln1	In0	Y
L	L	L	Н
L	L	Н	Н
L	Н	L	L
L	Н	Н	L
Н	L	L	Н
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	L

LOGIC DIAGRAM (POSITIVE LOGIC)

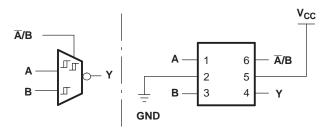


FUNCTION SELECTION TABLE

LOGIC FUNCTION	FIGURE NO.
2-to-1 data selector with inverted output	1
2-input NAND gate	2
2-input NOR gate with one inverted input	3
2-input AND gate with one inverted input	3
2-input NAND gate with one inverted input	4
2-input OR gate with one inverted input	4
2-input NOR gate	5
Noninverted buffer	6
Inverter	7



LOGIC CONFIGURATIONS



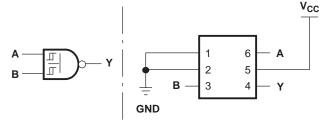
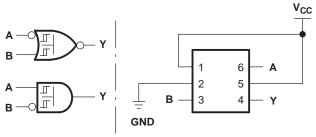
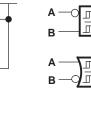


Figure 1. 2-to-1 Data Selector With Inverted Output

Figure 2. 2-Input NAND Gate





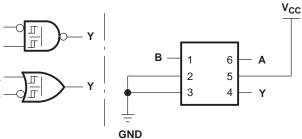
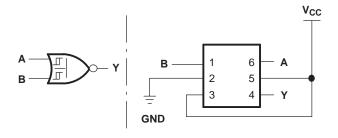


Figure 3. 2-Input NOR Gate With One Inverted Input 2-Input AND Gate With One Inverted Input

Figure 4. 2-Input NAND Gate With One Inverted Input 2-Input OR Gate With One Inverted Input



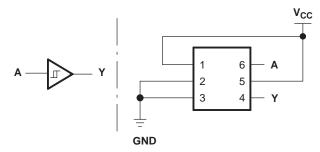


Figure 5. 2-Input NOR Gate

Figure 6. Noninverted Buffer

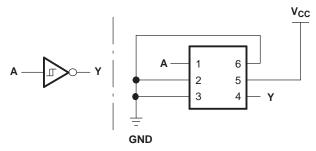


Figure 7. Inverter



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
V_{I}	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedance	or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low state	(2)(3)	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
0	Declare the weed in a decree (4)	DBV package		165	°C/W
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCK package		259	- C/VV
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
\ /	Curalizations	Operating	1.65	5.5	V
V _{CC}	Supply voltage	Data retention only	1.5		V
V_{I}	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
		V _{CC} = 2.3 V		-8	
I_{OH}	High-level output current	V 2V		-16	mA
		V _{CC} = 3 V		-24	
		V _{CC} = 4.5 V		-24	
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
I_{OL}	Low-level output current	V 2V		16	mA
		V _{CC} = 3 V		24	
		V _{CC} = 4.5 V		24	
T_A	Operating free-air temperature		-40	125	°C

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Submit Documentation Feedback

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

³⁾ The value of V_{CC} is provided in the recommended operating conditions table.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V _{CC}	MIN	TYP ⁽¹⁾	MAX	UNIT	
			1.65 V	0.6		1.4		
_ V _{T+}			2.3 V	1		1.8		
Positive-going input threshold			3 V	1.3		2.2	V	
voltage			4.5 V	1.9		3.1		
			5.5 V	2.2		3.6		
			1.65 V	0.3		0.7		
V_{T-}			2.3 V	0.5		1		
Negative-going input threshold			3 V	0.7		1.4	V	
voltage			4.5 V	1		2		
			5.5 V	1.2		2.3		
			1.65 V	0.3		0.8		
ΔV_{T}			2.3 V	0.4		0.9		
Hysteresis			3 V	0.5		1	V	
$(V_{T+} - V_{T-})$			4.5 V	0.6		1.5		
			5.5 V	0.7		1.7		
	$I_{OH} = -100 \mu A$		1.65 V to 5.5 V	V _{CC} - 0.2				
	I _{OH} = -4 mA		1.65 V	1.2				
	$I_{OH} = -8 \text{ mA}$		2.3 V	1.9			.,	
V _{OH}	I _{OH} = −16 mA		3 V	2.4			V	
	1 04 4		3 V	2.3				
	$I_{OH} = -24 \text{ mA}$		4.5 V	3.8				
	I _{OL} = 100 μA		1.65 V to 5.5 V			0.1		
	I _{OL} = 4 mA		1.65 V			0.45		
V	I _{OL} = 8 mA		2.3 V			0.3	V	
V _{OL}	I _{OL} = 16 mA		3 V			0.45	V	
	1 04 4		3 V			0.55		
	$I_{OL} = 24 \text{ mA}$		4.5 V			0.58		
I _I	V _I = 5.5 V or GND		0 to 5.5 V			±5	μΑ	
I _{off}	V_I or $V_O = 5.5 \text{ V}$		0			±10	μΑ	
I _{CC}	$V_I = 5.5 \text{ V or GND},$	I _O = 0	1.65 V to 5.5 V			10	μΑ	
ΔI _{CC}	One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND	3 V to 5.5 V			500	μΑ	
C _i	$V_I = V_{CC}$ or GND		3.3 V		3.5		pF	

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 8)

PARAMETER FROM (INPUT)		TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = 2 ± 0.2		V _{CC} = ± 0.3		V _{CC} =		UNIT
	(INPOT)	(0011 01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Any In	Y	3.2	16.4	2	9.3	1.5	7.3	1.1	6.1	ns

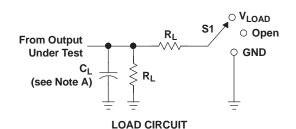
Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETER		TEST	V _{CC} = 1.8 V	$V_{CC} = 2.5 \text{ V}$	$V_{CC} = 3.3 \text{ V}$	$V_{CC} = 5 V$	UNIT
		CONDITIONS	TYP TYP		TYP	TYP	ONII
C_{pd}	Power dissipation capacitance	f = 10 MHz	23	23	23	26	pF

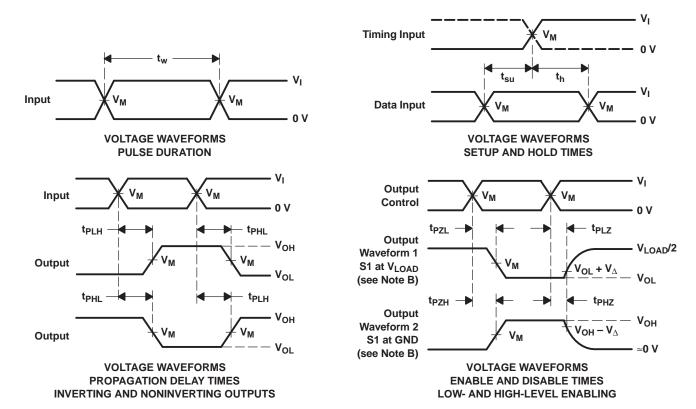


PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V_{LOAD}
t _{PHZ} /t _{PZH}	GND

V	INF	PUTS	V	V		Б	V
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_{Δ}
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V_{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	2×V _{CC}	50 pF	500 Ω	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω .
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 8. Load Circuit and Voltage Waveforms

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SN74LVC1G98QDCKRQ1	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	CWO
SN74LVC1G98QDCKRQ1.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	CWO

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G98-Q1:

Catalog: SN74LVC1G98

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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● Enhanced Product : SN74LVC1G98-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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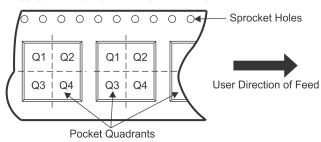
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G98QDCKRQ1	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74LVC1G98QDCKRQ1	SC70	DCK	6	3000	200.0	183.0	25.0	



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

 4. Falls within JEDEC MO-203 variation AB.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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